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CORRECTION

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Correction: The polarization-dependent anisotropic Raman response of few-layer and bulk WTe₂ under different excitation wavelengths

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Correction for 'The polarization-dependent anisotropic Raman response of few-layer and bulk WTe₂ under different excitation wavelengths' by Qingjun Song et al., RSC Adv., 2016, $\bf{6}$, 103830–103837.

In part (d) of Fig. 4 of the original manuscript, and in the description of part (d) in the Fig. 4 caption, the wrong labels were given for the modes. The labels "B_g" and "A_u" should be "B_u" and "A_g", respectively. The corrected Fig. 4 and its caption are shown below: Additionally, in the Results and Discussion section, in the text below Fig. 4, two sentences should be revised as follows:

"For $E_{\rm las} \approx 2.3$ eV, the excited electron will transit from the $A_{\rm g}$ valence band to $A_{\rm u}$ conductance band, and the corresponding polar plot is shown in Fig. 4(e), where the maximum (minimum) absorption corresponds to the perpendicular (parallel) relation between the incident polarization and a-axis".

"To study the influence of electron–photon interaction on the anisotropic Raman scattering, we first assume the electron–phonon interaction (H_{e-ph}) in the Raman scattering is not polarization dependent".

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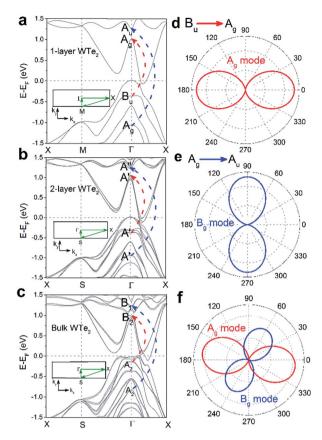


Fig. 4 (a–c) The calculated band structures of monolayer, bilayer and bulk WTe₂, respectively. The representative band symmetries at Γ point are labelled, and the insets are their 2D Brillouin zones. Calculated polarization dependence of the optical transition probability (d) from the B_u to A_g ($E_{las} \approx 1.5$ eV) and (e) from the A_g to A_u ($E_{las} \approx 2.3$ eV) in monolayer WTe₂, as indicated in (a). 0° corresponds to the W–W chain (a-axis) direction, the initial incident polarization and scattered polarization are along the a-axis ($\theta_0 = 0^\circ$). (f) The representative calculated polarization dependent intensities of A_g and B_g modes in monolayer WTe₂ with certain θ_0 (~15°).

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.